

Features

- High Density Cell Desihn for Low R_{DS(on)}
- Fully Characterized Avalanche Voltage and Current
- Excellent Package for Good Heat Dissipation
- Special Process Technology for High ESD Capability
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 62.5°C/W Junction to Ambient^(Note 2)

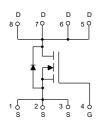
| Parameter | Symbol | Rating | Unit |
|----------------------------------|-----------------|--------|------|
| Drain-Source Voltage | V _{DS} | 30 | V |
| Gate-Source Volltage | V _{GS} | ±20 | V |
| Continuous Drain Current | I _D | 100 | А |
| Pulsed Drain Current | I _{DM} | 400 | А |
| Total Power Dissipation (Note 2) | P _D | 2 | W |

Note:

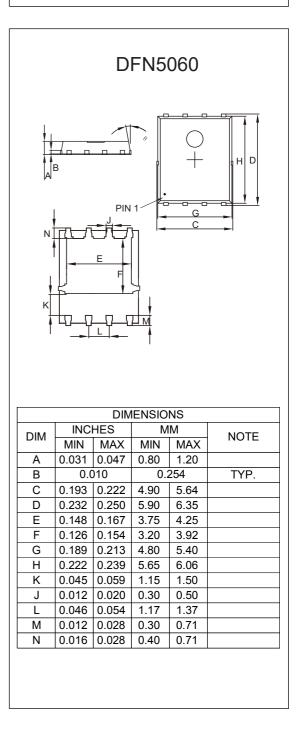
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

2. Mounted on a Glass Epoxy Board of 25.4mm x 25.4mm x 0.8mm.

Internal Structure



N-CHANNEL MOSFET





Electrical Characteristics @ 25°C (Unless Otherwise Specified)

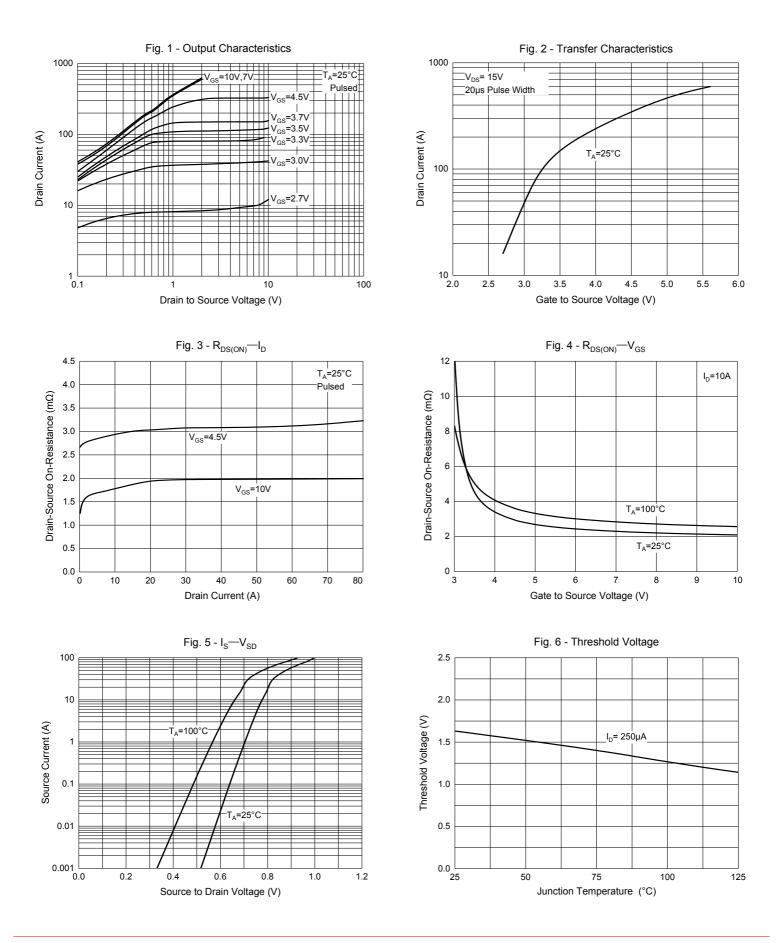
| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit |
|--|----------------------|--|-----|------|------|------|
| Static Characteristics | | | | L | I | L |
| Drain-Source Breakdown Voltage | V _{(BR)DSS} | V _{GS} =0V, I _D =250µA | 30 | | | V |
| Gate-Source Leakage Current | I _{GSS} | V _{DS} =0V, V _{GS} =±20V | | | ±100 | nA |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =30V, V _{GS} =0V | | | 1 | μA |
| Gate-Threshold Voltage ^(Note 3) | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250µA | 1.2 | 1.7 | 2.5 | V |
| Drain-Source On-Resistance ^(Note 3) | R _{DS(on)} | V _{GS} =10V, I _D =20A | | 1.9 | 2.5 | - mΩ |
| | | V _{GS} =4.5V, I _D =10A | | 2.9 | 3.5 | |
| Forward Tranconductance ^(Note 3) | g fs | V _{DS} =10V, I _D =20A | 32 | | | S |
| Dynamic Characteristics ^(Note 4) | | | | | | |
| Input Capacitance | C _{iss} | V _{DS} =15V,V _{GS} =0V,f=1MHz | | 5000 | | pF |
| Output Capacitance | C _{oss} | | | 1135 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 563 | | |
| Total Gate Charge | Qg | V _{DS} =15V,V _{GS} =10V,I _D =20A | | 38 | | |
| Gate-Source Charge | Q _{gs} | | | 9 | | nC |
| Gate-Drain Charge | Q _{gd} | | | 13 | | |
| Turn-On Delay Time | t _{d(on)} | | | 26 | | |
| Turn-On Rise Time | t _r | V _{DD} =15V, R _L =15Ω V _{GS} =10V,R _G =2.5Ω | | 24 | | - ns |
| Turn-Off Delay Time | t _{d(off)} | | | 91 | | |
| Turn-Off Fall Time | t _f | | | 39 | | |
| Drain-Source Body Diode Cha | racteristi | cs | | , | 1 | 1 |
| Continuous Body Diode Current | I _S | | | | 100 | A |
| Pulsed Diode Forward Current | I _{SM} | | | | 400 | |
| Body Diode Voltage (Note 3) | V _{SD} | I _S =10A, V _{GS} =0V | | | 1.2 | V |

Note 3. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤2%.

4. Guaranteed by Design, Not Subject to Production Testing.



Curve Characteristics





Ordering Information

| Device | Packing | |
|----------------|-----------------------|--|
| Part Number-TP | Tape&Reel: 5Kpcs/Reel | |

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